

International
IR Rectifier

16CTQ...G

SCHOTTKY RECTIFIER

16 Amp

$$I_{F(AV)} = 16 \text{ Amp}$$

$$V_R = 60/100V$$

Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	16	A
V_{RRM}	60/100	V
I_{FSM} @ tp = 5 μ s sine	650	A
V_F @ 8 Apk, $T_J = 125^\circ\text{C}$ (per leg)	0.58	V
T_J range	-55 to 175	$^\circ\text{C}$

Description/ Features

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

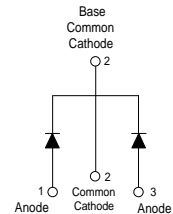
- 175° C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles

16CTQ...G



TO-220



Voltage Ratings

Parameters	16CTQ060G	16CTQ80G	16CTQ100G
V_R Max. DC Reverse Voltage (V)	60	80	100
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	16CTQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current (Per Leg) * See Fig. 5 (Per Device)	8	A	50% duty cycle @ $T_C = 148^\circ\text{C}$, rectangular wave form
	16		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	650	A	5 μs Sine or 3 μs Rect. pulse 10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated V_{RWM} applied
	210		
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	7.50	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 0.50$ Amps, $L = 60$ mH
I_{AR} Repetitive Avalanche Current (Per Leg)	0.50	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	16CTQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.72	V	@ 8A $T_J = 25^\circ\text{C}$
	0.88	V	@ 16A
	0.58	V	@ 8A $T_J = 125^\circ\text{C}$
	0.69	V	@ 16A
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	0.28	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	7.0	mA	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	0.415	V	$T_J = T_J \text{ max.}$
r_t Forward Slope Resistance	11.07	m Ω	
C_T Max. Junction Capacitance (Per Leg)	500	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance (Per Leg)	8.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	16CTQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 175	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case Per Leg	3.25	$^\circ\text{C/W}$	DC operation * See Fig. 4
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.50	$^\circ\text{C/W}$	Mounting surface, smooth and greased
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
	Max.	12 (10)	
Device Marking	16CTQ...G		

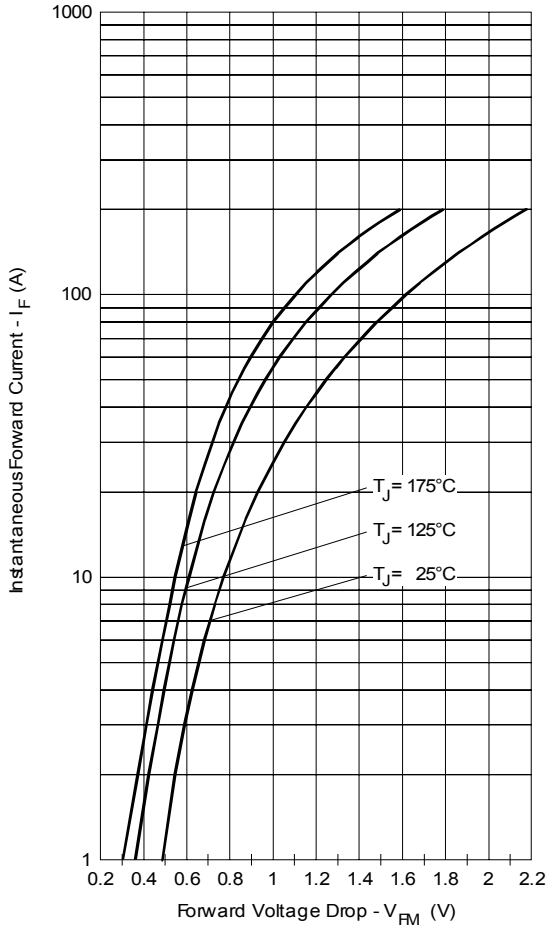


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

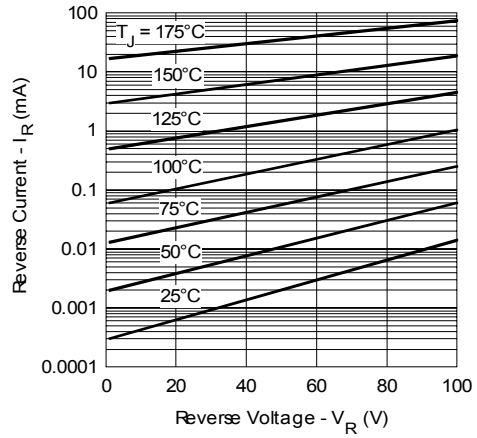


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

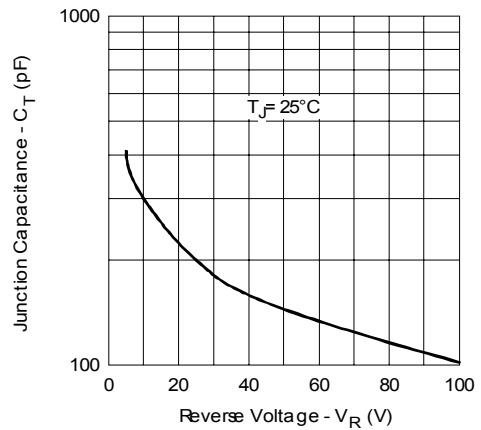


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

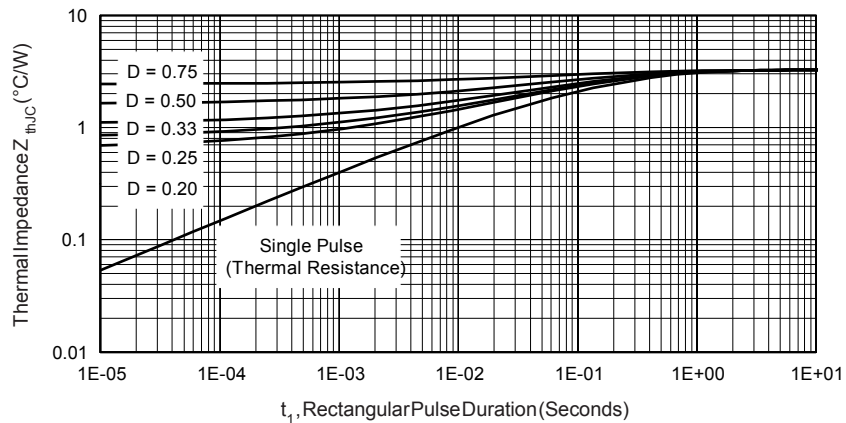


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

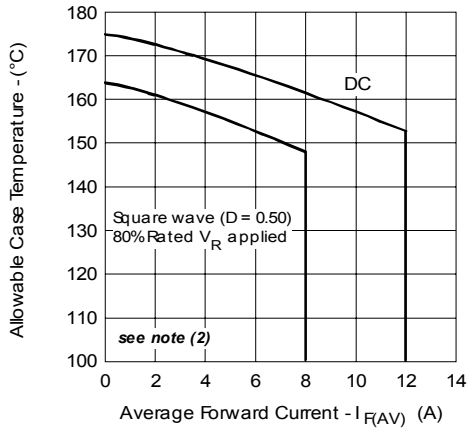


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

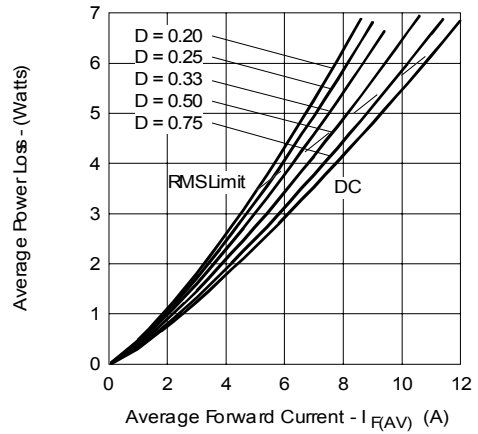


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

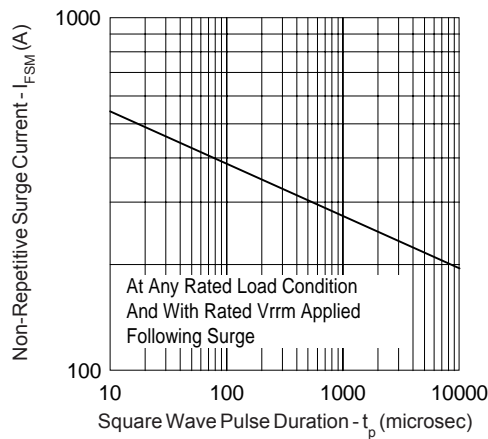


Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

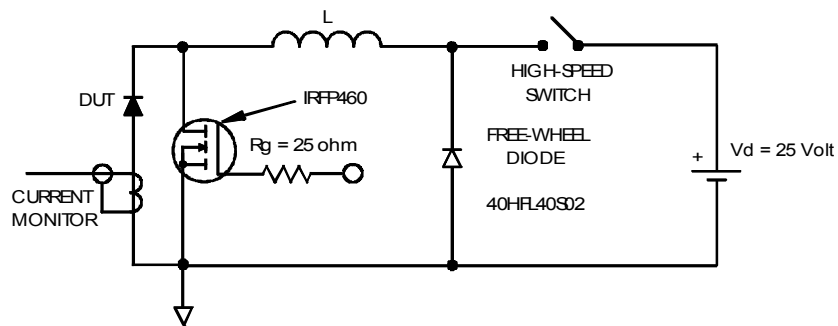


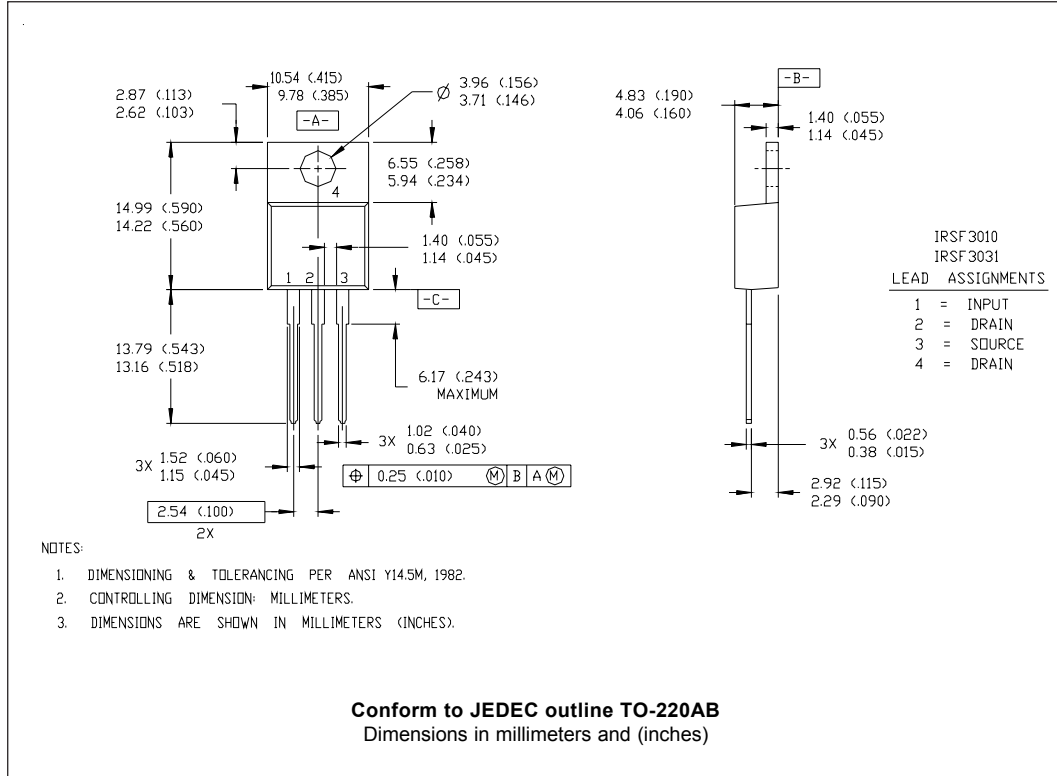
Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

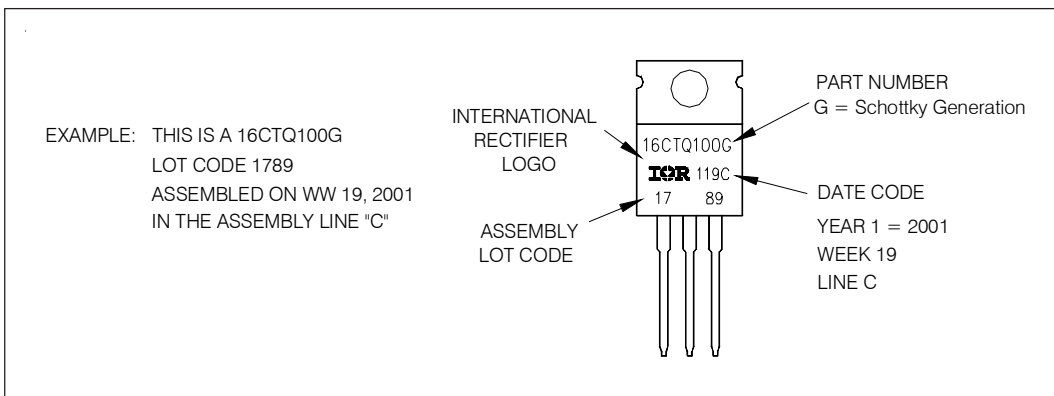
P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 10V$

Outline Table



Part Marking Information



Ordering Information Table

Device Code								
	<table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="padding: 5px;">16</td> <td style="padding: 5px;">C</td> <td style="padding: 5px;">T</td> <td style="padding: 5px;">Q</td> <td style="padding: 5px;">100</td> <td style="padding: 5px;">G</td> <td style="padding: 5px;">-</td> </tr> </table>	16	C	T	Q	100	G	-
16	C	T	Q	100	G	-		
	<table style="display: inline-table; border: none;"> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> <td style="text-align: center;">⑦</td> </tr> </table>	①	②	③	④	⑤	⑥	⑦
①	②	③	④	⑤	⑥	⑦		
1	- Current Rating (16 = 16A)							
2	- C = Common Cathode							
3	- T = TO-220							
4	- Q = Schottky Q Series							
5	- Voltage Ratings							
6	- G = Schottky Generation							
7	- <ul style="list-style-type: none"> • none = Standard Production • PbF = Lead-Free 							

060 = 60V
 080 = 80V
 100 = 100V

Tube Standard Pack Quantity : 50 pieces

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16CTQ100
*****
* SPICE Model Diode *
*****
.SUBCKT 16CTQ100 ANO CAT
D1 ANO 1 DMOD (0.07089)
*Define diode model
.MODEL DMOD D(IS=21.21E-06,N=1.578,RS=7.804E-03,Ikf=0.9497, Xti=2, Eg=1.11
+ Cjo=1.278E-09, M=0.4736, Vj=0.4972, Fc=0.5, Isr =1.114e-21, Nr=4.755,
+ Bv=119.9, Ibv=215.5E-06, Tt=18.2E-09)
*****

.ENDS 16CTQ100

Thermal Model Subcircuit
.SUBCKT 16CTQ100 5 1

CTHERM1 5 4 1.45E+00
CTHERM2 4 3 4.54E+00
CTHERM3 3 2 1.09E+01
CTHERM4 2 1 1.01E+02

R THERM1 5 4 2.49E+00
R THERM2 4 3 5.20E-04
R THERM1 3 2 5.43E-01
R THERM1 2 1 3.05E-02

.ENDS 16CTQ100
  
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Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.